## IN THE CLAIMS:

Please amend claims 1, 6, 7, 14, 19, and 20 as indicated below.

A listing of the status of all claims 1-20 in the present patent application is provided below.

- 1 (Currently Amended). A non-volatile electronic memory configuration comprising:
  - a volatile memory having a first port and a second port;
- a non-volatile memory coupled to the second port of the volatile memory;
- a controller coupled to both the first port and the second port of the volatile memory and the non-volatile memory that wo action to monitor data storage changes made within the volatile memory and controls control the transfer of stored data from the volatile memory to the non-volatile memory, and viceversa, based upon the monitored data storage changes when power is above a particular minimum operating voltage level; and
- a power level detector that detects when power is above the particular minimum operating voltage level.
- 2 (Previously Presented). The configuration of claim 1, further comprising:

a power storage element that stores transient power for use by at least one of the volatile memory, the non-volatile memory, and the controller when power is below the particular minimum operating voltage level.

- 3 (Previously Presented). The configuration of claim 2, wherein the controller controls the transfer of stored data from the volatile memory to the non-volatile memory based upon the monitored data storage changes for a limited period of time using the transient power stored by the power storage element when power is below the particular minimum operating voltage level.
- 4 (Original). The configuration of claim 2, wherein the power storage element comprises bulk capacitance having a value in the hundreds of microfarads.
- 5 (Previously Presented). The configuration of claim 1, wherein the volatile memory is a dynamic random access memory.
- 6 (Currently Amended). The configuration of claim [[5]] 1/2, wherein the volatile memory is a dual port, dynamic random access memory, wherein the controller is coupled to a first port

of the dual port, dynamic random access memory, and wherein both

the controller and the non-volatile memory are coupled to a second port of the dual port, dynamic random access memory

controller monitors data storage changes made within the

volatile memory via the first port.

7 (Currently Amended). The configuration of claim 1, wherein the volatile memory is a dual port, volatile memory, wherein the controller is coupled to a first port of the dual port, volatile memory, and wherein both the controller and the non volatile memory are coupled to a second port of the dual port, volatile memory controller controls the transfer of stored data from the second port of the volatile memory to the non-volatile memory.

- 8 (Previously Presented). The configuration of claim 1, wherein the non-volatile memory operates at a lower speed than the volatile memory.
- 9 (Original). The configuration of claim 1, wherein the non-volatile memory is a non-volatile flash memory.
- 10 (Original). The configuration of claim 1, wherein the controller is one of a microprocessor, a microcontroller, a

programmable processing device, and a fixed function processing device.

- 11 (Previously Presented). The configuration of claim 1, wherein the controller prevents the transfer of stored data from the volatile memory to the non-volatile memory, and vice-versa, when power is below the particular minimum operating voltage level for more than a limited period of time.
- 12 (Previously Presented). The configuration of claim 1, wherein the controller controls the transfer of stored data from the non-volatile memory to the volatile memory immediately following a restoration of power to above the particular minimum operating voltage level.
- 13 (Original). The configuration of claim 1, wherein the power level detector provides an indication to the controller that power is above the particular minimum operating voltage level.
- 14 (Currently Amended). A method for controlling data storage, the method comprising:

monitoring data storage changes made within a volatile memory having a first port and a second port, wherein the data

storage changes made within the volatile memory via the first port are monitored;

controlling the transfer of stored data from the second port of the volatile memory to a non-volatile memory, and viceversa, based upon the monitored data storage changes when power is above a particular minimum operating voltage level; and

preventing stored data to be from being transferred from the second port of the volatile memory to the non-volatile memory, and vice-versa, when power is below the particular minimum operating voltage level.

- 15 (Original). The method of claim 14, further comprising:

  detecting when power is above the particular minimum operating voltage level.
- 16 (Original). The method of claim 15, further comprising:

  providing an indication that power is above the particular minimum operating voltage level.
- 17 (Original). The method of claim 14, further comprising:

  detecting when power is below the particular minimum operating voltage level.

18 (Original). The method of claim 17, further comprising:

providing an indication that power is below the particular minimum operating voltage level.

19 (Currently Amended). The method of claim 18, further comprising:

providing a transient power when power is below the particular minimum operating voltage level; and

controlling the transfer of stored data from the second port of the volatile memory to [[a]] the non-volatile memory based upon the monitored data storage changes for a limited period of time using the transient power when power is below the particular minimum operating voltage level.

20 (Currently Amended). The method of claim 14, further comprising:

controlling the transfer of stored data from the non-volatile memory to the second port of the volatile memory immediately following a restoration of power to above the particular minimum operating voltage level.